

BUK7Q8R4-40H

Standard level N-Channel MOSFET in MLPAK33-WF (SOT8002-3D)

28 August 2025

Product data sheet

1. General description

Standard level N-Channel MOSFET in a compact MLPAK33-WF (SOT8002-3D) package using Trench 9 technology. This product has been designed and qualified to meet AEC-Q101 requirements delivering high performance and reliability.

2. Features and benefits

- Trench 9 technology Designed for ruggedness
- Small footprint (3 x 3 mm) for compact design
- Qualified to AEC-Q101 at 175 °C
- · Side-wettable flanks for robust solder joints and automated optical inspection

3. Applications

- Motor drive
- Battery protection
- DC-DC Conversion

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	40	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>		-	-	57	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	51	W
Static chara	cteristics						
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 15 A; T_j = 25 °C; Fig. 11		4.9	7	8.4	mΩ
Dynamic cha	aracteristics		·				
Q_{GD}	gate-drain charge	I_D = 15 A; V_{DS} = 20 V; V_{GS} = 10 V; T_j = 25 °C; Fig. 13; Fig. 14		-	3	6	nC



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	1 2 3 4 	
2	S	source		D
3	S	source		
4	G	gate		_G (LE本)
mb	D	Mounting base; connected to drain	MLPAK33-WF (SOT8002-3)	mbb076 S

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BUK7Q8R4-40H		plastic thermal enhanced surface mounted package with side-wettable flanks (SWF); mini leads; 8 terminals;pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body	SOT8002-3		

7. Marking

Table 4. Marking codes

Type number	Marking code
BUK7Q8R4-40H	1NE

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Tj = 25 °C unless otherwise stated.

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C	-	40	V
V _{GS}	gate-source voltage		-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>	-	51	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	-	57	Α
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>	-	40	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; Fig. 3	-	226	А
T _{stg}	storage temperature		-55	175	°C
Tj	junction temperature		-55	175	°C
Source-drain d	iode			·	
Is	source current	T _{mb} = 25 °C	-	43	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 ^{\circ}C$	-	226	А

Symbol	Parameter	Conditions		Min	Max	Unit
Avalanche rugg	edness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$\begin{split} I_D &= 25 \text{ A; } V_{sup} \leq \text{ 40 V; } R_{GS} = 50 \Omega; \\ V_{GS} &= 10 \text{ V; } T_{j(init)} = 25 \text{ °C; } unclamped; \\ t_p &= 90 \mu\text{s; } \underline{Fig. 4} \end{split}$	[1] [2]	-	58.7	mJ
I _{AS}	non-repetitive avalanche current	$V_{sup} \le 40 \text{ V}; V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ °C};$ $R_{GS} = 50 \Omega; Fig. 4$	[3]	-	48	Α

- [1] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.
- [2] Refer to application note AN10273 for further information.
- [3] Protected by 100% test

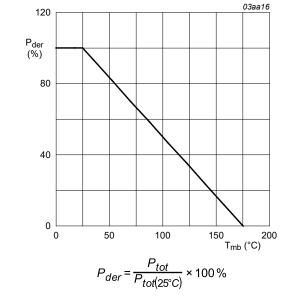


Fig. 1. Normalized total power dissipation as a function of mounting base temperature

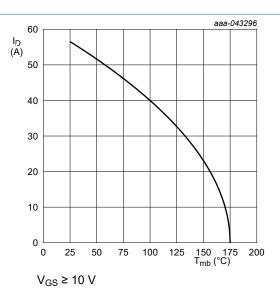
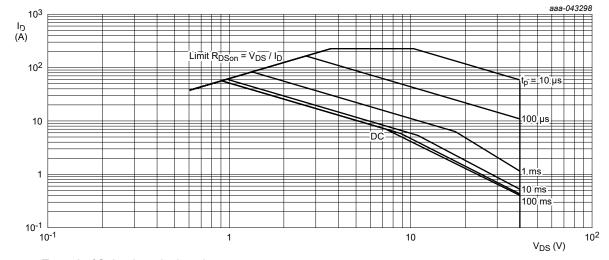
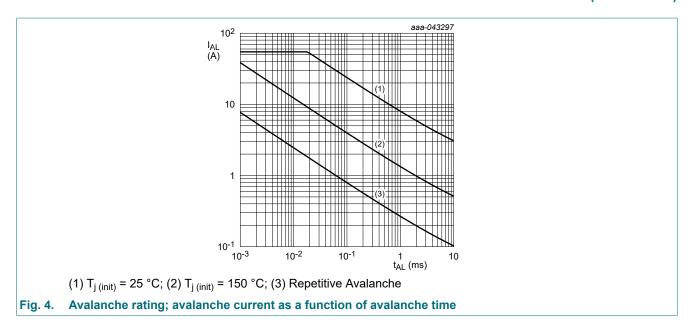


Fig. 2. Continuous drain current as a function of mounting base temperature



 T_{mb} = 25 °C; I_{DM} is a single pulse

Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5		-	2.44	2.92	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient		[1]	-	-	40	K/W

[1] Device on 4 layer PCB. Refer to TN00008 for further information.



10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _i = 25 °C	40	44	-	V
,	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _i = -40 °C	-	40.5	-	V
		I _D = 250 μA; V _{GS} = 0 V; T _i = -55 °C	36	40	-	V
$V_{GS(th)}$	gate-source threshold voltage	I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 25 °C; <u>Fig. 9</u> ; <u>Fig. 10</u>	2.4	3	3.6	V
		I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 175 °C; Fig. 10	1	-	-	V
		I _D = 1 mA; V _{DS} =V _{GS} ; T _j = -55 °C; <u>Fig. 10</u>	-	-	4.3	V
I _{DSS}	drain leakage current	V _{DS} = 40 V; V _{GS} = 0 V; T _j = 25 °C	-	0.01	1	μA
		V _{DS} = 40 V; V _{GS} = 0 V; T _j = 175 °C	-	-	500	μΑ
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
		V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 15 A; T_j = 25 °C; Fig. 11	4.9	7	8.4	mΩ
		V_{GS} = 10 V; I_D = 15 A; T_j = 105 °C; Fig. 12	6.5	9.3	12.4	mΩ
		V _{GS} = 10 V; I _D = 15 A; T _j = 125 °C; Fig. 12	7.1	10	13.5	mΩ
		V _{GS} = 10 V; I _D = 15 A; T _j = 175 °C; Fig. 12	8.4	12	16	mΩ
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	1	2.5	6.3	Ω
Dynamic ch	naracteristics					<u>'</u>
Q _{G(tot)}	total gate charge	I _D = 15 A; V _{DS} = 20 V; V _{GS} = 10 V;	-	16	22	nC
Q _{GS}	gate-source charge	T _j = 25 °C; <u>Fig. 13</u> ; <u>Fig. 14</u>	-	5	7.5	nC
Q _{GD}	gate-drain charge		-	3	6	nC
C _{iss}	input capacitance	V _{DS} = 25 V; V _{GS} = 0 V; f = 1 MHz;	-	1093	1530	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 15</u>	-	293	410	pF
C _{rss}	reverse transfer capacitance	-	-	56	123	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 20 \text{ V}; R_L = 1.3 \Omega; V_{GS} = 10 \text{ V};$	-	4.7	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	4.3	-	ns
t _{d(off)}	turn-off delay time		-	13	-	ns
t _f	fall time		-	4.3	-	ns
Source-dra	in diode			<u> </u>		
V _{SD}	source-drain voltage	$I_S = 15 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}; Fig. 16$	-	0.8	1.2	V
t _{rr}	reverse recovery time	$I_S = 15 \text{ A}$; $dI_S/dt = -100 \text{ A/}\mu\text{s}$; $V_{GS} = 0 \text{ V}$;	-	18	-	ns
Q _r	recovered charge	V _{DS} = 20 V; T _j = 25 °C; <u>Fig. 17</u>	[1] -	10	-	nC

^[1] includes capacitive recovery

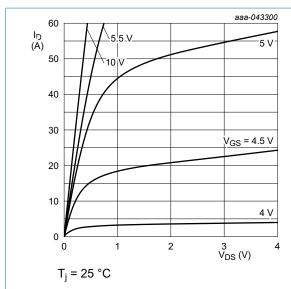


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

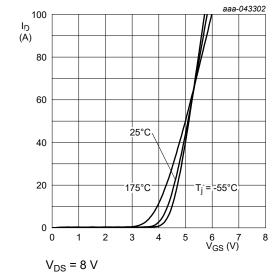


Fig. 8. Transfer characteristics; drain current as a function of gate-source voltage; typical values

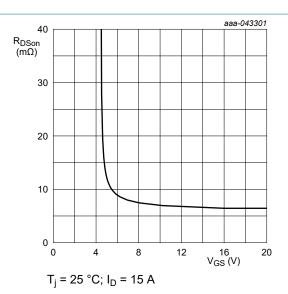


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

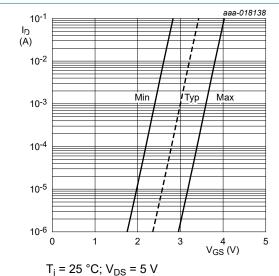


Fig. 9. Sub-threshold drain current as a function of gate-source voltage

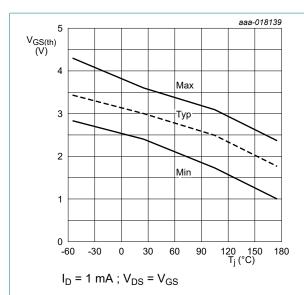


Fig. 10. Gate-source threshold voltage as a function of junction temperature

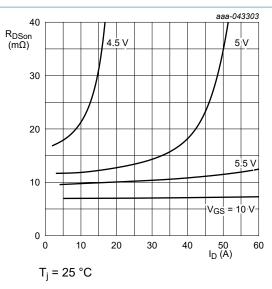


Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

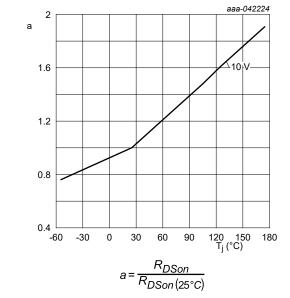


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

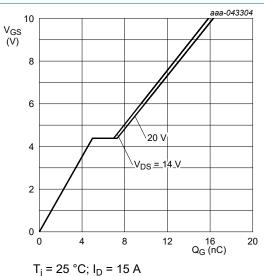


Fig. 13. Gate-source voltage as a function of gate charge; typical values

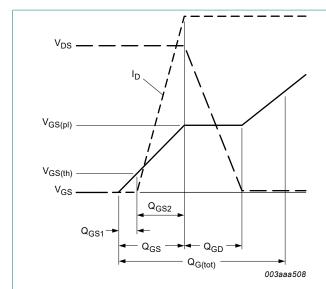


Fig. 14. Gate charge waveform definitions

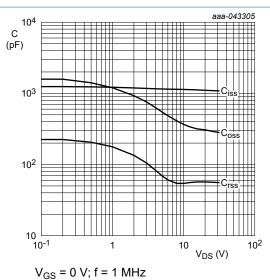


Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

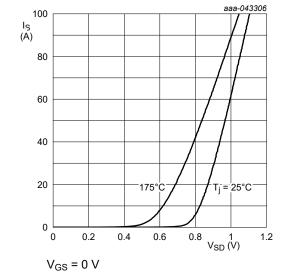


Fig. 16. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

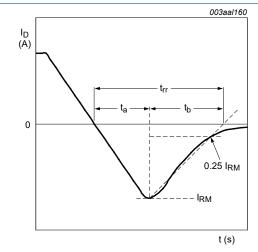
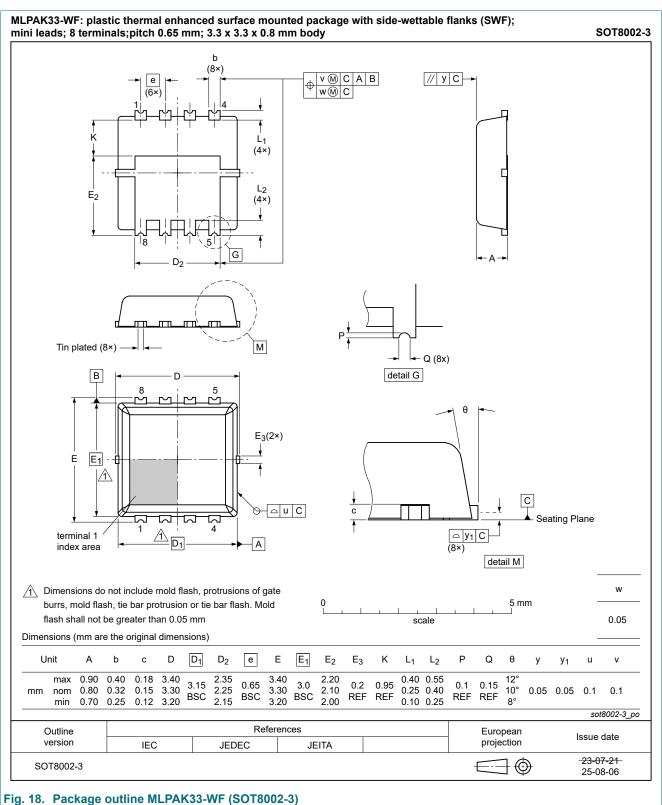
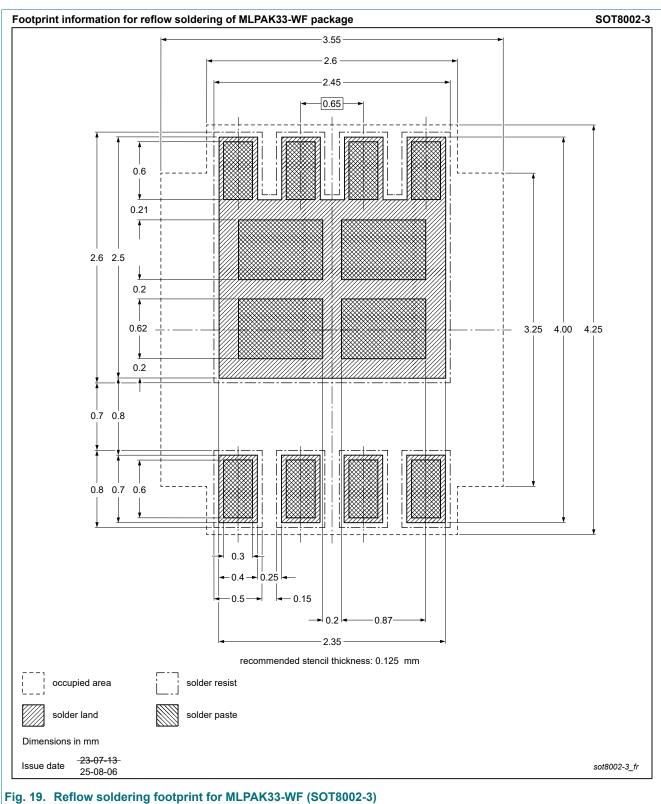


Fig. 17. Reverse recovery timing definition

11. Package outline



12. Soldering



13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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